

Single 2-input NOR gate

1. Description

The 74LVC1G02 provides the single 2-input NOR function. Input can be driven from either 3.3V or 5V devices. These features allow the use of these devices in a mixed 3.3V and 5V environment. Schmitt-trigger action at all inputs makes the circuit tolerant for slower input rise and fall time. This device is fully specified for partial power-down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

2. Features

- Wide supply voltage range from 1.65V to 5.5V
- $\pm 24\text{mA}$ output drive ($V_{CC}=3.0\text{V}$)
- CMOS low power consumption
- Latch-up performance exceeds 250mA
- Direct interface with TTL levels
- Inputs accept voltages up to 5V
- Specified from -40°C to $+105^{\circ}\text{C}$
- Packaging information: SOT-23-5/SOT-353

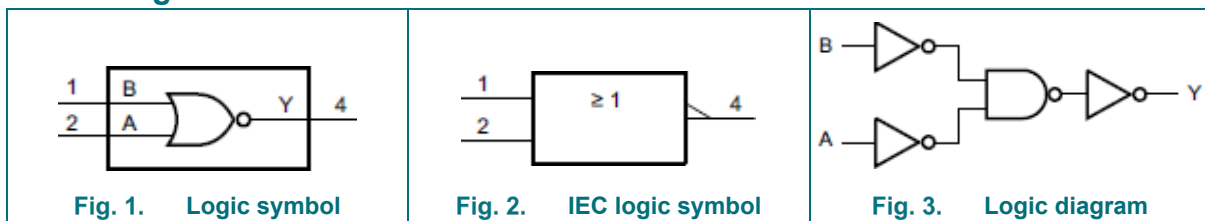
3. Ordering Information

Type Number	Package Type	Packing	Notes
74LVC1G02DBV	SOT-23-5	Tape & Reel	
74LVC1G02DCK	SOT-353	Tape & Reel	

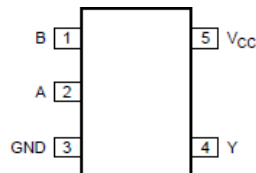
Note: If the physical information is inconsistent with the ordering information, please refer to the actual product.

4. Block Diagram and Pin Description

Block Diagram



Pin Configurations



Pin Description

Pin No.	Pin Name	Description
1	B	data input
2	A	data input
3	GND	ground (0V)
4	Y	data output
5	V_{CC}	supply voltage

Function Table

Input		Output
A	B	Y
L	L	H
L	H	L
H	L	L
H	H	L

Note: H=HIGH voltage level; L=LOW voltage level.

5. Electrical Parameter

Absolute Maximum Ratings

(Voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Max.	Unit
supply voltage	V_{CC}	-	-0.5	+6.5	V
input clamping current	I_{IK}	$V_I < 0V$	-50	-	mA
input voltage	V_I	-	-0.5	+6.5	V
output clamping current	I_{OK}	$V_O > V_{CC}$ or $V_O < 0V$	-	± 50	mA
output voltage	V_O	Active mode	-0.5	$V_{CC}+0.5$	V
		Power-down mode	-0.5	+6.5	V
output current	I_O	$V_O=0V$ to V_{CC}	-	± 50	mA
supply current	I_{CC}	-	-	100	mA
ground current	I_{GND}	-	-100	-	mA
total power dissipation	P_{tot}	-	-	250	mW
storage temperature	T_{stg}	-	-65	+150	°C
Soldering temperature	T_L	10s	250		°C

Note: When $V_{CC}=0V$ (Power-down mode), the output voltage can be 5.5V in normal operation.

Recommended Operating Conditions

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
supply voltage	V_{CC}	-	1.65	-	5.5	V
input voltage	V_I	-	0	-	5.5	V
output voltage	V_O	Active mode	0	-	V_{CC}	V
		Power-down mode; $V_{CC}=0V$	0	-	5.5	V
ambient temperature	T_{amb}	-	-40	-	+105	°C
input transition rise and fall rate	$\Delta t/\Delta V$	$V_{CC}=1.65V$ to $2.7V$	-	-	20	ns/V
		$V_{CC}=2.7V$ to $5.5V$	-	-	10	ns/V

6. Electrical Characteristics

DC Characteristics 1

($T_{amb} = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit	
HIGH-level input voltage	V_{IH}	$V_{CC}=1.65\text{V}$ to 1.95V	$0.65 \times V_{CC}$	-	-	V	
		$V_{CC}=2.3\text{V}$ to 2.7V	1.7	-	-	V	
		$V_{CC}=2.7\text{V}$ to 3.6V	2.0	-	-	V	
		$V_{CC}=4.5\text{V}$ to 5.5V	$0.7 \times V_{CC}$	-	-	V	
LOW-level input voltage	V_{IL}	$V_{CC}=1.65\text{V}$ to 1.95V	-	-	$0.35 \times V_{CC}$	V	
		$V_{CC}=2.3\text{V}$ to 2.7V	-	-	0.7	V	
		$V_{CC}=2.7\text{V}$ to 3.6V	-	-	0.8	V	
		$V_{CC}=4.5\text{V}$ to 5.5V	-	-	$0.3 \times V_{CC}$	V	
HIGH-level output voltage	V_{OH}	$V_I = V_{IH}$ or V_{IL}	$I_O = -100\mu\text{A}$; $V_{CC}=1.65\text{V}$ to 5.5V	$V_{CC} - 0.1$	-	-	V
			$I_O = -4\text{mA}$; $V_{CC}=1.65\text{V}$	1.2	-	-	V
			$I_O = -8\text{mA}$; $V_{CC}=2.3\text{V}$	1.9	-	-	V
			$I_O = -12\text{mA}$; $V_{CC}=2.7\text{V}$	2.2	-	-	V
			$I_O = -24\text{mA}$; $V_{CC}=3.0\text{V}$	2.3	-	-	V
			$I_O = -32\text{mA}$; $V_{CC}=4.5\text{V}$	3.8	-	-	V
LOW-level output voltage	V_{OL}	$V_I = V_{IH}$ or V_{IL}	$I_O = 100\mu\text{A}$; $V_{CC}=1.65\text{V}$ to 5.5V	-	-	0.10	V
			$I_O = 4\text{mA}$; $V_{CC}=1.65\text{V}$	-	-	0.45	V
			$I_O = 8\text{mA}$; $V_{CC}=2.3\text{V}$	-	-	0.30	V
			$I_O = 12\text{mA}$; $V_{CC}=2.7\text{V}$	-	-	0.40	V
			$I_O = 24\text{mA}$; $V_{CC}=3.0\text{V}$	-	-	0.55	V
			$I_O = 32\text{mA}$; $V_{CC}=4.5\text{V}$	-	-	0.55	V
input leakage current	I_I	$V_I = 5.5\text{V}$ or GND; $V_{CC} = 0\text{V}$ to 5.5V	-	± 0.1	± 1	μA	
power-off leakage current	I_{OFF}	V_I or $V_O = 5.5\text{V}$; $V_{CC} = 0\text{V}$	-	± 0.1	± 2	μA	
supply current	I_{CC}	$V_I = 5.5\text{V}$ or GND; $I_O = 0\text{A}$; $V_{CC} = 1.65\text{V}$ to 5.5V	-	0.1	4	μA	
additional supply current	ΔI_{CC}	per pin; $V_I = V_{CC} - 0.6\text{V}$; $I_O = 0\text{A}$; $V_{CC} = 2.3\text{V}$ to 5.5V	-	5	500	μA	
input capacitance	C_I	$V_{CC} = 3.3\text{V}$; $V_I = \text{GND}$ to V_{CC}	-	5	-	pF	

Note: All typical values are measured at $V_{CC} = 3.3\text{V}$ and $T_{amb} = 25^{\circ}\text{C}$.

DC Characteristics 2

($T_{amb} = -40^{\circ}\text{C}$ to $+105^{\circ}\text{C}$, voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit	
HIGH-level input voltage	V_{IH}	$V_{CC}=1.65\text{V}$ to 1.95V	$0.65 \times V_{CC}$	-	-	V	
		$V_{CC}=2.3\text{V}$ to 2.7V	1.7	-	-	V	
		$V_{CC}=2.7\text{V}$ to 3.6V	2.0	-	-	V	
		$V_{CC}=4.5\text{V}$ to 5.5V	$0.7 \times V_{CC}$	-	-	V	
LOW-level input voltage	V_{IL}	$V_{CC}=1.65\text{V}$ to 1.95V	-	-	$0.35 \times V_{CC}$	V	
		$V_{CC}=2.3\text{V}$ to 2.7V	-	-	0.7	V	
		$V_{CC}=2.7\text{V}$ to 3.6V	-	-	0.8	V	
		$V_{CC}=4.5\text{V}$ to 5.5V	-	-	$0.3 \times V_{CC}$	V	
HIGH-level output voltage	V_{OH}	$V_I = V_{IH}$ or V_{IL}	$I_o = -100\mu\text{A}$; $V_{CC}=1.65\text{V}$ to 5.5V	$V_{CC} - 0.1$	-	-	V
			$I_o = -4\text{mA}$; $V_{CC}=1.65\text{V}$	0.95	-	-	V
			$I_o = -8\text{mA}$; $V_{CC}=2.3\text{V}$	1.7	-	-	V
			$I_o = -12\text{mA}$; $V_{CC}=2.7\text{V}$	1.9	-	-	V
			$I_o = -24\text{mA}$; $V_{CC}=3.0\text{V}$	2.0	-	-	V
			$I_o = -32\text{mA}$; $V_{CC}=4.5\text{V}$	3.4	-	-	V
LOW-level output voltage	V_{OL}	$V_I = V_{IH}$ or V_{IL}	$I_o = 100\mu\text{A}$; $V_{CC}=1.65\text{V}$ to 5.5V	-	-	0.10	V
			$I_o = 4\text{mA}$; $V_{CC}=1.65\text{V}$	-	-	0.70	V
			$I_o = 8\text{mA}$; $V_{CC}=2.3\text{V}$	-	-	0.45	V
			$I_o = 12\text{mA}$; $V_{CC}=2.7\text{V}$	-	-	0.60	V
			$I_o = 24\text{mA}$; $V_{CC}=3.0\text{V}$	-	-	0.80	V
			$I_o = 32\text{mA}$; $V_{CC}=4.5\text{V}$	-	-	0.80	V
input leakage current	I_I	$V_I=5.5\text{V}$ or GND; $V_{CC}=0\text{V}$ to 5.5V	-	-	± 1	μA	
power-off leakage current	I_{OFF}	V_I or $V_o=5.5\text{V}$; $V_{CC}=0\text{V}$	-	-	± 2	μA	
supply current	I_{CC}	$V_I=5.5\text{V}$ or GND; $I_o=0\text{A}$; $V_{CC}=1.65\text{V}$ to 5.5V	-	-	4	μA	
additional supply current	ΔI_{CC}	per pin; $V_I=V_{CC}-0.6\text{V}$; $I_o=0\text{A}$; $V_{CC}=2.3\text{V}$ to 5.5V	-	5	500	μA	

Note: All typical values are measured at $V_{CC}=3.3\text{V}$ and $T_{amb}=25^{\circ}\text{C}$.

AC Characteristics 1

($T_{amb} = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit	
A, B to Y propagation delay	t_{pd}	see Figure 5	$V_{CC} = 1.65\text{V to } 1.95\text{V}$	1.0	3.2	8.0	ns
			$V_{CC} = 2.3\text{V to } 2.7\text{V}$	0.5	2.2	5.5	ns
			$V_{CC} = 2.7\text{V}$	0.5	2.5	5.5	ns
			$V_{CC} = 3.0\text{V to } 3.6\text{V}$	0.5	2.1	4.5	ns
			$V_{CC} = 4.5\text{V to } 5.5\text{V}$	0.5	1.7	4.0	ns
Power dissipation capacitance	C_{PD}	$V_{CC} = 3.3\text{V}; V_I = \text{GND to } V_{CC}$	-	14	-	pF	

Note:

- 1 Typical values are measured at $T_{amb} = 25^{\circ}\text{C}$ and $V_{CC} = 1.8\text{V}, 2.5\text{V}, 2.7\text{V}, 3.3\text{V}$ and 5.0V respectively.
- 2 t_{pd} is the same as t_{PLH} and t_{PHL} .
- 3 C_{PD} is used to determine the dynamic power dissipation (P_D in μW). $P_D = (C_{PD} \times V_{CC}^2 \times f_i \times N) + \sum (C_L \times V_{CC}^2 \times f_o)$ where:

f_i = input frequency in MHz; f_o = output frequency in MHz; C_L = output load capacitance in pF; V_{CC} = supply voltage in V; N = number of inputs switching.

AC Characteristics 2

($T_{amb} = -40^{\circ}\text{C}$ to $+105^{\circ}\text{C}$, voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit	
A, B to Y propagation delay	t_{pd}	see Figure 5	$V_{CC} = 1.65\text{V to } 1.95\text{V}$	1.0	-	10.5	ns
			$V_{CC} = 2.3\text{V to } 2.7\text{V}$	0.5	-	7.0	ns
			$V_{CC} = 2.7\text{V}$	0.5	-	7.0	ns
			$V_{CC} = 3.0\text{V to } 3.6\text{V}$	0.5	-	6.0	ns
			$V_{CC} = 4.5\text{V to } 5.5\text{V}$	0.5	-	5.5	ns

Note:

- 1 Typical values are measured at $T_{amb} = 25^{\circ}\text{C}$ and $V_{CC} = 1.8\text{V}, 2.5\text{V}, 2.7\text{V}, 3.3\text{V}$ and 5.0V respectively.
- 2 t_{pd} is the same as t_{PLH} and t_{PHL} .

7. Testing Circuit

AC Testing Circuit

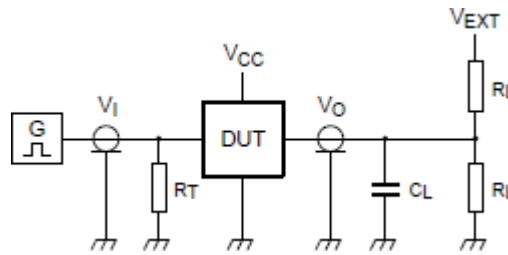


Fig. 4. Figure 4. Test circuit for measuring switching times

Definitions for test circuit:

R_L =Load resistance.

C_L =Load capacitance including jig and probe capacitance.

R_T =Termination resistance; should be equal to the output impedance Z_o of the pulse generator.

V_{EXT} =External voltage for measuring switching times.

AC Testing Waveforms

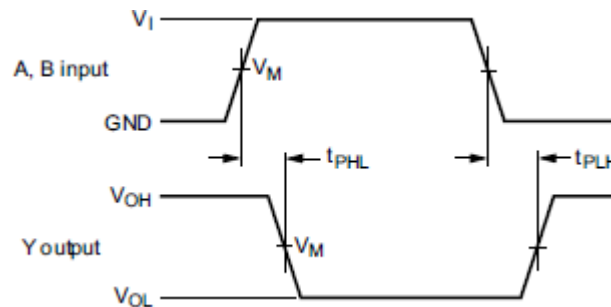


Fig. 5. The input A, B to output Y propagation delays

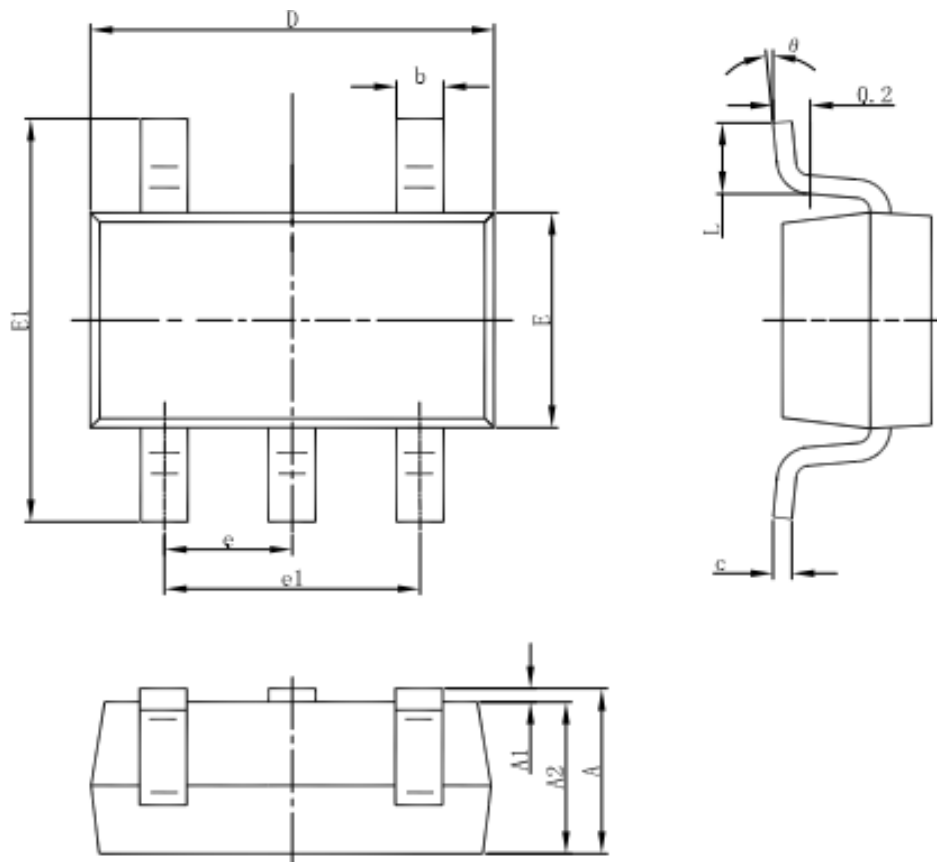
Measurement Points

Supply voltage	Input	Output
V_{CC}	V_M	V_M
1.65V to 1.95V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$
2.3V to 2.7V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$
2.7V	1.5V	1.5V
3.0V to 3.6V	1.5V	1.5V
4.5V to 5.5V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$

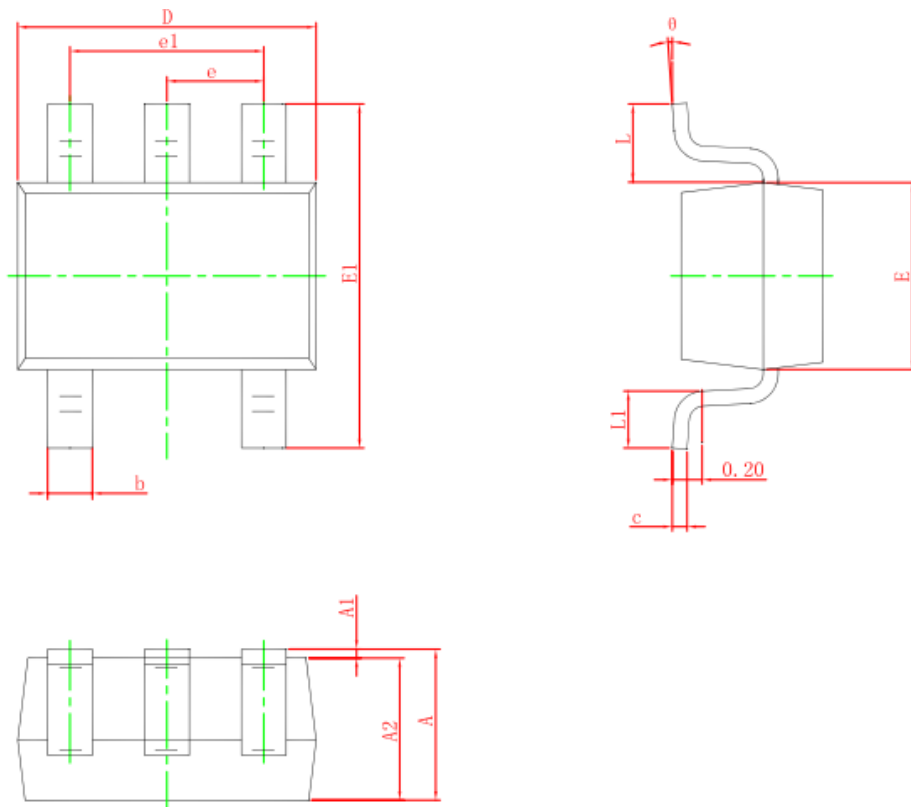
Test Data

Supply voltage	Input		Load		V_{EXT}
V_{CC}	V_I	$t_r = t_f$	C_L	R_L	t_{PLH}, t_{PHL}
1.65V to 1.95V	V_{CC}	$\leq 2.0ns$	30pF	1k Ω	open
2.3V to 2.7V	V_{CC}	$\leq 2.0ns$	30pF	500 Ω	open
2.7V	2.7V	$\leq 2.5ns$	50pF	500 Ω	open
3.0V to 3.6V	2.7V	$\leq 2.5ns$	50pF	500 Ω	open
4.5V to 5.5V	V_{CC}	$\leq 2.5ns$	50pF	500 Ω	open

8. Package Outlines

SOT-23-5


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
e	0.950(BSC)		0.037(BSC)	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

SOT-353


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.100	0.035	0.043
A1	0.000	0.100	0.000	0.004
A2	0.900	1.000	0.035	0.039
b	0.150	0.350	0.006	0.014
c	0.080	0.150	0.003	0.006
D	2.000	2.200	0.079	0.087
E	1.150	1.350	0.045	0.053
E1	2.150	2.450	0.085	0.096
e	0.650 TYP.		0.026 TYP.	
e1	1.200	1.400	0.047	0.055
L	0.525 REF.		0.021 REF.	
L1	0.260	0.460	0.010	0.018
θ	0°	8°	0°	8°

9. Disclaimers

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